Complementary Dual General Purpose Amplifier Transistor

PNP and NPN Surface Mount

Features

- High Voltage and High Current: $V_{CEO} = 50 \text{ V}$, $I_C = 200 \text{ mA}$
- High h_{FE} : $h_{FE} = 200 \sim 400$
- Moisture Sensitivity Level: 1
- ESD Rating Human Body Model: 3A
 - Machine Model: C
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	60	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	7.0	Vdc
Collector Current - Continuous	Ic	200	mAdc

THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D	187 (Note 1) 256 (Note 2) 1.5 (Note 1) 2.0 (Note 2)	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	670 (Note 1) 490 (Note 2)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D	250 (Note 1) 385 (Note 2) 2.0 (Note 1) 3.0 (Note 2)	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	493 (Note 1) 325 (Note 2)	°C/W
Thermal Resistance, Junction-to-Lead	$R_{ heta JL}$	188 (Note 1) 208 (Note 2)	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

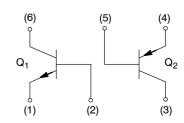
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 x 1.0 inch Pad



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SC-88 CASE 419B

MARKING DIAGRAM



3Z = Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device*	Package	Shipping [†]		
UMZ1NT1G	SC-88 (Pb-Free)	3000 / Tape & Reel		

*The "T1" suffix refers to a 7 inch reel.

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Q1: NPN ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

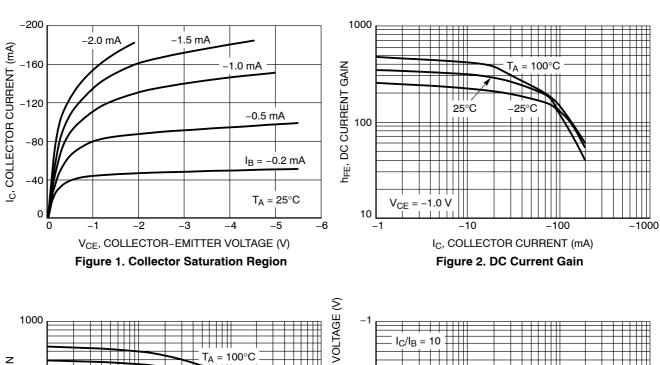
Characteristic	Symbol	Min	Тур	Max	Unit
Collector–Emitter Breakdown Voltage $(I_C = 2.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	50	-	_	Vdc
Collector–Base Breakdown Voltage ($I_C = 10 \mu Adc, I_E = 0$)	V _{(BR)CBO}	60	-	-	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$)	V _{(BR)EBO}	7.0	-	_	Vdc
Collector–Base Cutoff Current (V _{CB} = 45 Vdc, I _E = 0)	I _{CBO}	_	-	0.1	μAdc
	I _{CEO}	- - -	- - -	0.1 2.0 1.0	μAdc μAdc mAdc
DC Current Gain (Note 3) (V _{CE} = 6.0 Vdc, I _C = 2.0 mAdc)	h _{FE}	200	-	400	-
Collector–Emitter Saturation Voltage (I _C = 100 mAdc, I _B = 10 mAdc)	V _{CE(sat)}	0.15	-	0.25	Vdc
Transistor Frequency	f _T	-	114	-	MHz

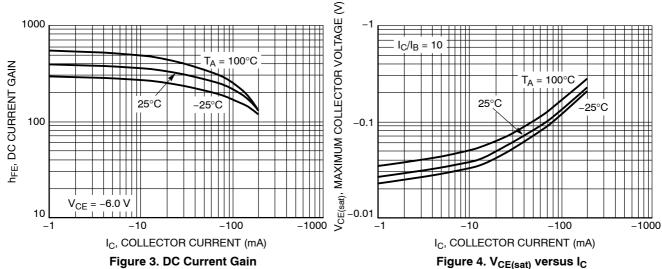
^{3.} Pulse Test: Pulse Width \leq 300 $\mu\text{s},\ D.C. \leq$ 2%.

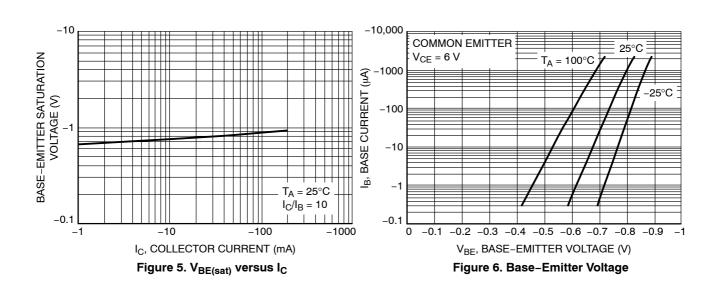
Q2: PNP
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Collector-Emitter Breakdown Voltage (I _C = 2.0 mAdc, I _B = 0)	V _{(BR)CEO}	-50	-	_	Vdc
Collector–Base Breakdown Voltage ($I_C = 10 \mu Adc, I_E = 0$)	V _{(BR)CBO}	-60	-	-	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$)	V _{(BR)EBO}	-7.0	-	_	Vdc
Collector–Base Cutoff Current (V _{CB} = 45 Vdc, I _E = 0)	I _{CBO}	-	-	-0.1	μAdc
	I _{CEO}	- - -	- - -	-0.1 -2.0 -1.0	μAdc μAdc mAdc
DC Current Gain (Note 3) (V _{CE} = 6.0 Vdc, I _C = 2.0 mAdc)	h _{FE}	200	-	400	-
Collector–Emitter Saturation Voltage (I _C = 100 mAdc, I _B = 10 mAdc)	V _{CE(sat)}	-0.15	-	-0.3	Vdc
Transistor Frequency	f _T	_	142	-	MHz

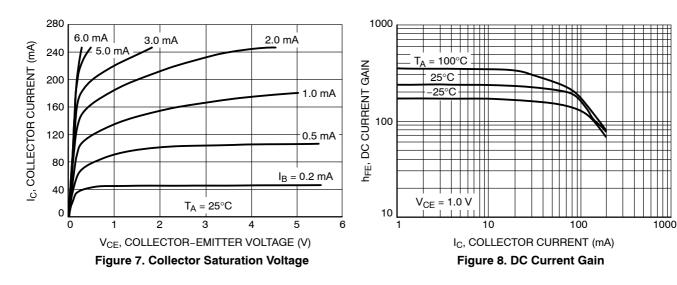
TYPICAL ELECTRICAL CHARACTERISTICS: PNP TRANSISTOR

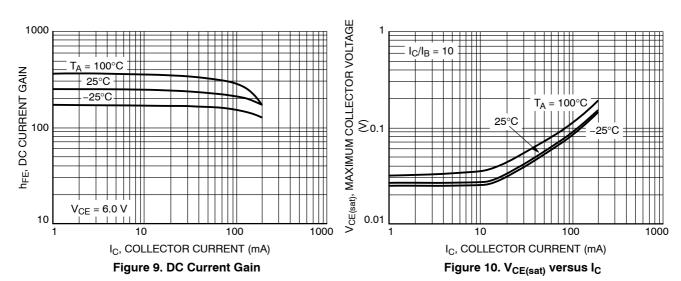


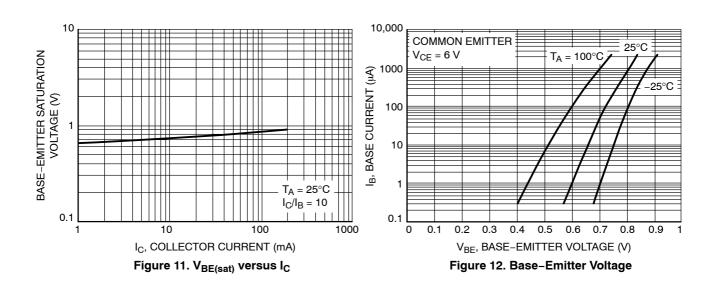




TYPICAL ELECTRICAL CHARACTERISTICS: NPN TRANSISTOR

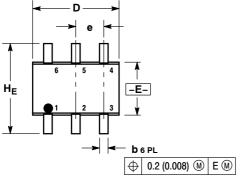


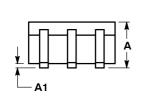


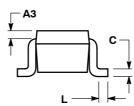


PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE W





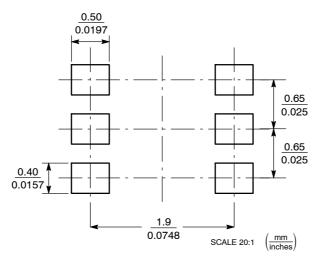


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 YA4 5M 4000
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
- 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.95	1.10	0.031	0.037	0.043	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
А3		0.20 REF			0.008 REF		
b	0.10	0.21	0.30	0.004	0.008	0.012	
C	0.10	0.14	0.25	0.004	0.005	0.010	
D	1.80	2.00	2.20	0.070	0.078	0.086	
Е	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65 BSC			0.026 BSC			
L	0.10	0.20	0.30	0.004	0.008	0.012	
Н-	2 00	2 10	2 20	0.078	0.082	0.086	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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